

Features

Low forward voltage drop
High reverse voltage
Hermetic metal cases with ceramic insulators

Typical Applications

All purpose high power rectifier diodes
High power resistance welding equipment
Non-controllable and half-controllable rectifiers
Controlled rectifiers

Part No. Y38ZPB-ZT33cT		
$I_{F(AV)}$	**1700A**	
V_{RRM}	**200V**	**400V**
	600V	**800V**
	1000V	**1200V**
	1400V	

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T_j(C)	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180 half sine wave 50Hz Double side cooled,	T_C=85 C	190			1700	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms		190	200		1400	V
I_{RRM}	Repetitive peak current	at V_{RRM}		190			40	mA
I_{FSM}	Surge forward current	10ms half sine wave V_R=0.6V_{RRM}		190			18	kA
I^2t	I^2t for fusing coordination						1620	A^2s*10^3
V_{FO}	Threshold voltage			190			0.81	V
r_F	Forward slope resistance						0.23	mΩ
V_{FM}	Peak forward voltage	I_{FM}=2400A, F=15kN		25			2.0	V
Q_{rr}	Recovery charge	I_{FM}=1000A, tp=4000μs, di/dt=-20A/μs, V_R=100V		190		1900		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180^0 sine double side cooled Clamping force 15.0kN					0.035	C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink						0.008	
F_m	Mounting force				10		20	kN
T_{vj}	Junction temperature				-40		190	C
T_{stg}	Stored temperature				-40		190	C
W_t	Weight					240		g
Outline	ZT33cT							

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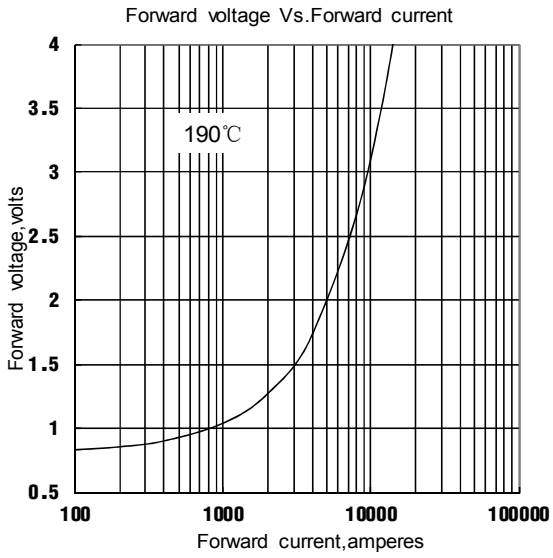


Fig.1

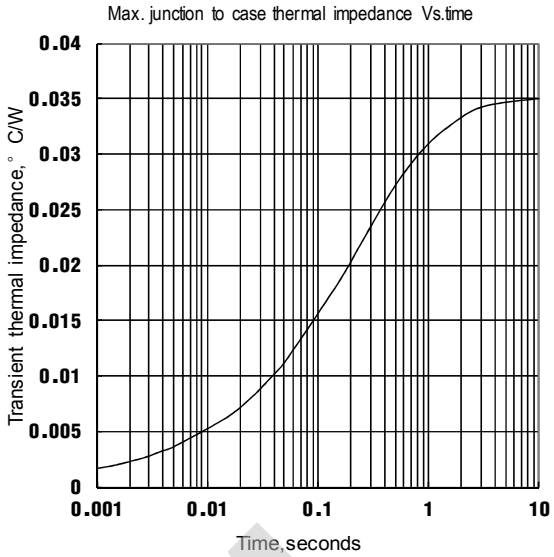


Fig.2

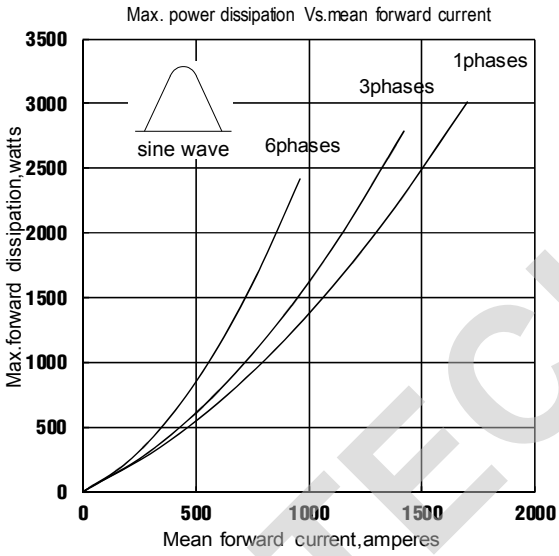


Fig.3

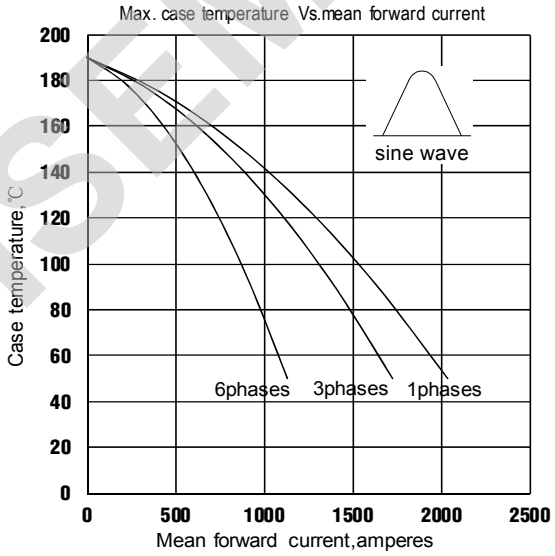


Fig.4

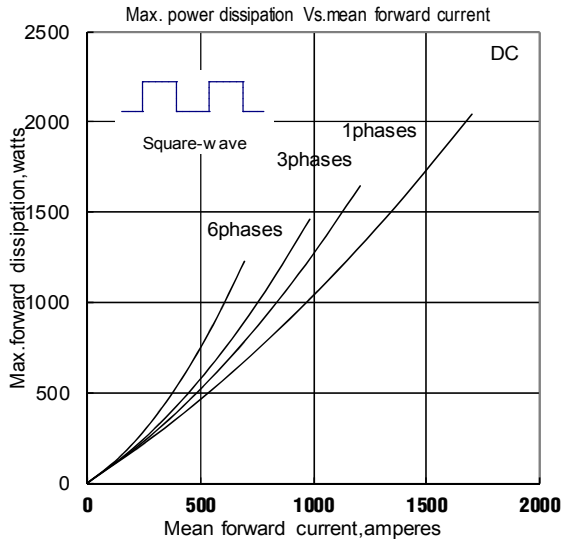


Fig.5

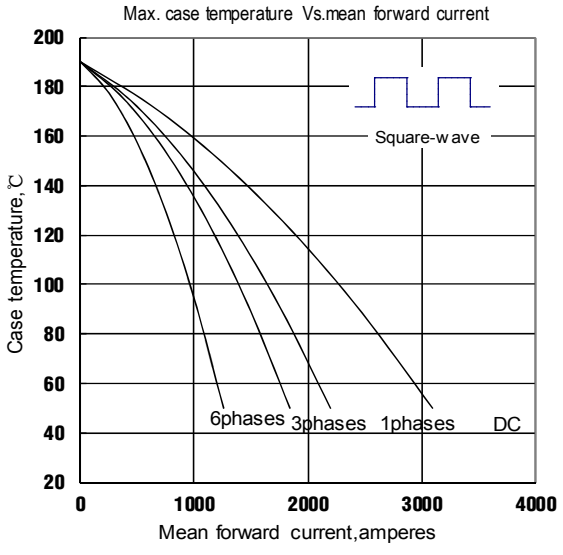


Fig.6

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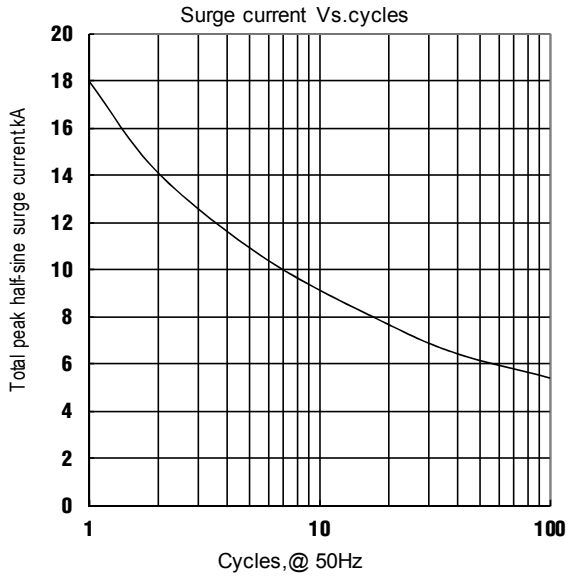


Fig.7

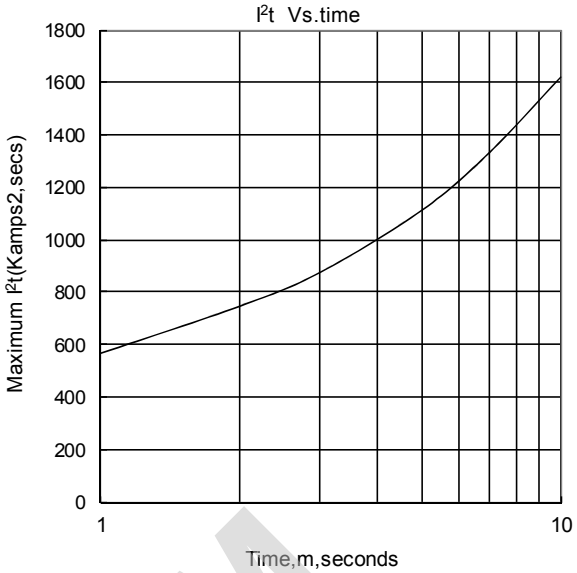
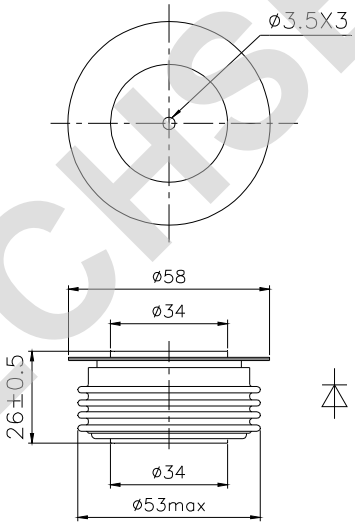


Fig.8

Outline:



TECHSEM reserves the right to change specifications without notice.

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